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INFORMATION DISCLOSURE CITATION (Use several sheets if the cessary)									
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ELECTRONIC INFORMATION DISCLOSURE STATEMENT

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Title of Invention

BIPOLAR TRANSISTOR HAVING RAISED EXTRINSIC BASE WITH SELECTABLE SELF-ALIGNMENT AND METHODS OF FORMING SAME

Application Number:

Confirmation Number:

First Named Applicant:

Marwan Khater

Attorney Docket Number:

FIS920030097US1

Art Unit:

Examiner:

Search string:

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or 5723378 or 5766999 or 5789800 or 5798561 or 5821149 or 5834800 or 5846869

or 5962880 or 6121101 or 6281097 or 6287929 or 6329698 or 6337251 or 6346453

or 6380017 or 6383855 or 6388307).pn

US Patent Documents

Note: Applicant is not required to submit a paper copy of cited US Patent Documents

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Signature

Examiner Name	Date		
PHUCT. DANG	11/10/2004		